



An Effective Surface Impedance Concept to Model Arbitrary Roughness Profiles on Printed Circuit Boards up to 110 GHz

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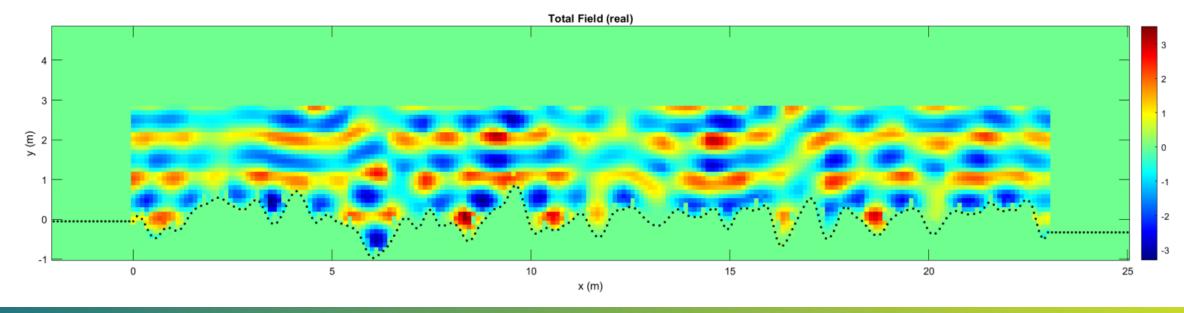




Introduction



- Many ways to describe impact of rough surfaces on highfrequency signals.
- Famous: H&J, Huray (snowball), full-wave stochastic models,
 Gradient Model



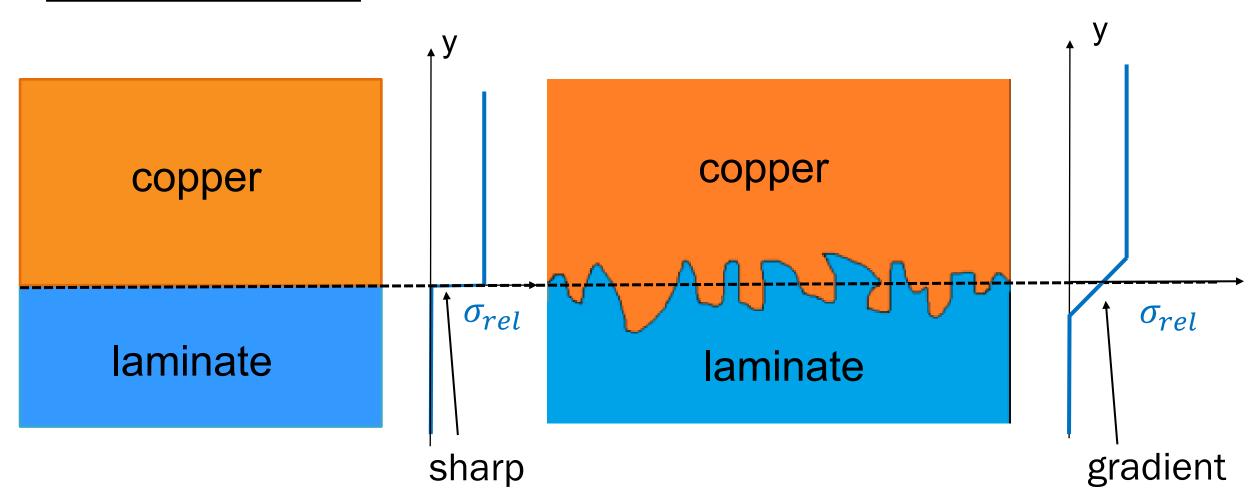




Gradient Model









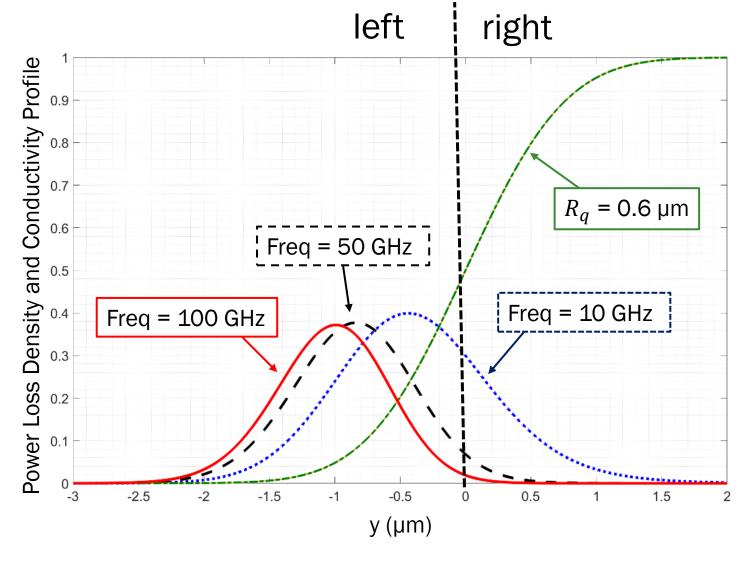


Typical Profile Approximation



Roughness profiles often approximated as CDF of a gaussian bell curve with gradient R_q :

Most of the power loss on left side of Profile!

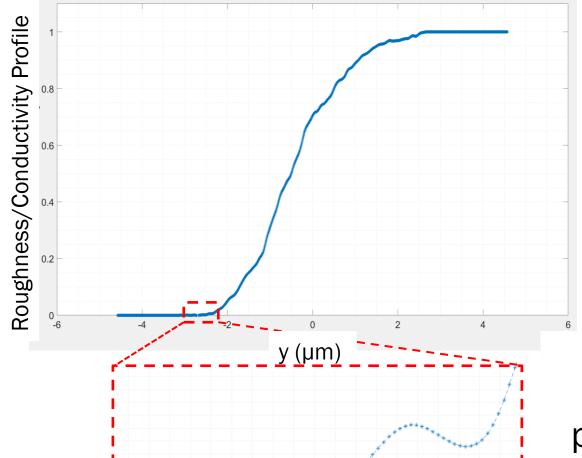






Real Roughness Profiles





-2.7

y (µm)

-2.6

-2.5

original:

$$\frac{\partial^2 \underline{B}_x^L}{\partial y^2} - j\omega\mu\sigma\underline{B}_x^L - \frac{\partial}{\partial y}\ln(\sigma(y))\frac{\partial\underline{B}_x^L}{\partial y} = 0$$

$$\ln(0) = -\inf!!$$

E-field formular:

$$\frac{\partial^2 \underline{E}_{x}^{L}}{\partial y^2} - j\omega\mu\sigma(y)\underline{E}_{x}^{L} = 0$$

power loss:
$$P_v = \int \sigma(y) \left| \underline{E}_x^L \right|^2 dy$$

current: $\underline{I} = \int \sigma(y) \underline{E}_x^L dy$

current:
$$\underline{I} = \int \sigma(y) \underline{E}_x^L dy$$

$$\underline{R} = \frac{P_{v}}{\underline{I}^{2}}$$



-2.8



Effective R_q Concept



Calculate R for a given profile and desired frequency

Estimate, which gaussian CDF with gradient $R_{q,eff}$ has same \underline{R} as calculated from the real profile





Problems with Curve Approximations

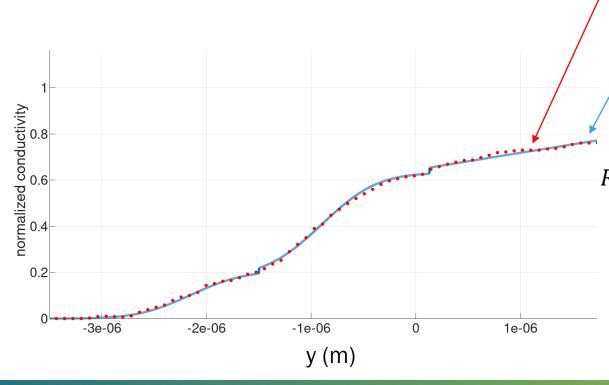






Measurement

Approximation with 3 gaussian CDFs



Fit with single, gaussian CDF

$$R_{q,eff,single\ CDF} = 2.39 \ \mu m$$

$$R_{q,eff\ DIN\ EN\ ISO\ 4287} = 2.45 \ \mu m$$

$$R_{q,eff,three\ CDF} = 0.74 \ \mu m$$

3 different approximations with total different results (@ 50 GHz)!!

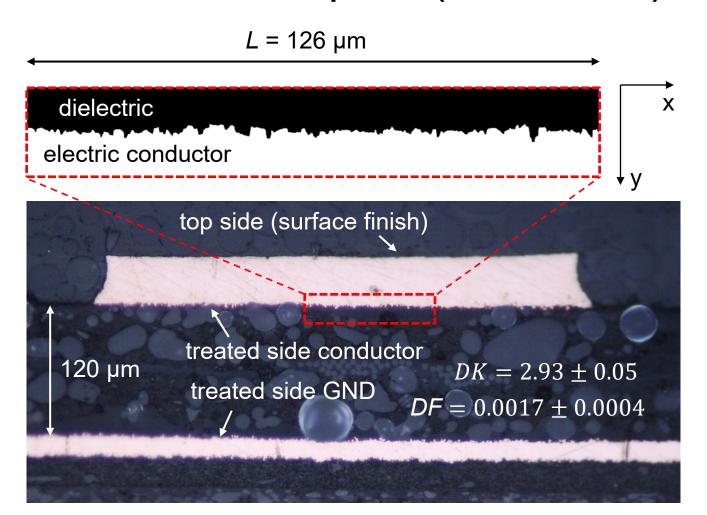




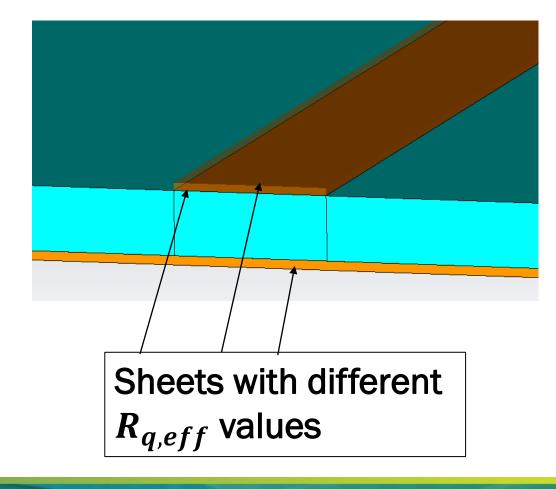
Considered Materials



Real world Microstrip Line (cross-section):



Simulation model:



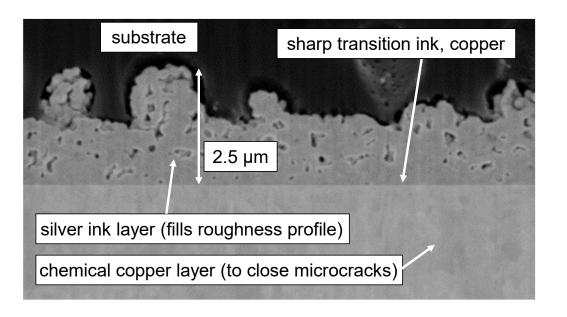




IMS Same Substrate, Different Conductor

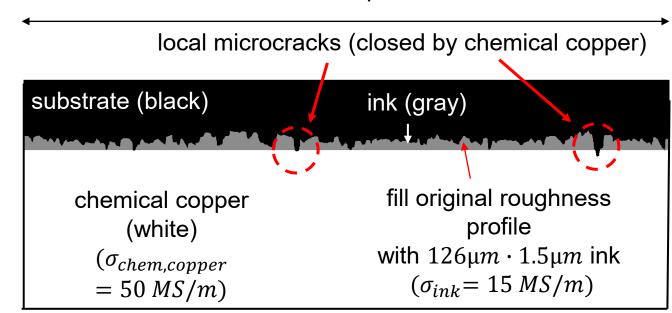


FIB-Cut of an ink/chemical copper layer-stack:



model:

126 µm







Insertion Loss of 1.57 inch long MS



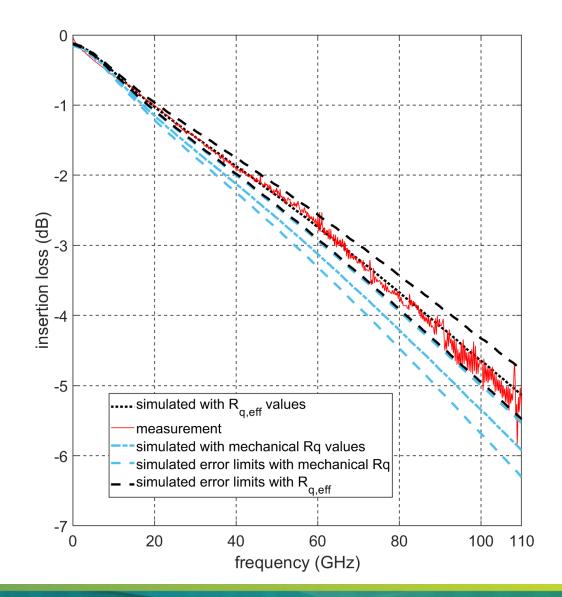
Conductor = pure copper (trace height = $50 \mu m$):

$$R_{q,treated,side} = \sqrt{\frac{1}{L} \int_0^L h(x)^2 dx} = 0.85 \mu m \pm 0.1 \mu m$$

$$R_{q,eff,treated \, side} = 0.65 \mu m \pm 0.1 \mu m$$

 $R_{q,eff,top \, side} = 0.25 \mu m \pm 0.05 \mu m$

Only with $R_{q,eff}$ plausible simulation results!!







Insertion Loss of 1.57 inch long MS

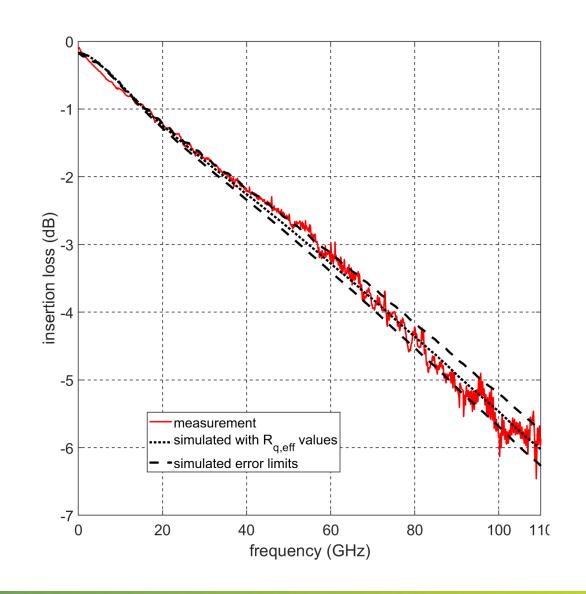


Conductor = ink/chem. Copper layerstack (trace height = 5µm):

$$R_{q,eff,treated} = 0.86 \mu m \pm 0.1 \mu m$$

$$R_{q,eff,top \ side} = 0.44 \mu m \pm 0.11 \mu m$$

Excellent agreement between measurement and simulation

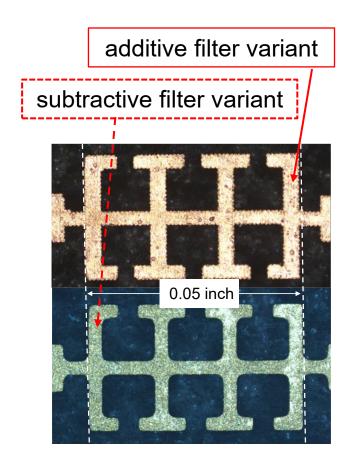


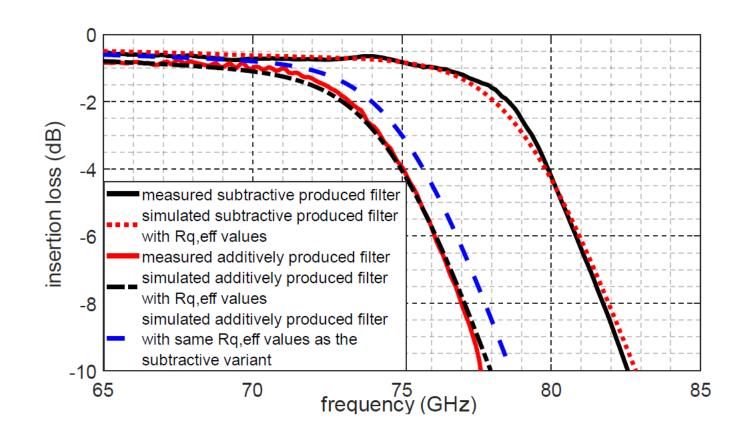




Low-Pass Filters











Summary



Main idea of the Gradient Model is adopted
Surface impedance is calculated from real profiles
An effective surface roughness parameter is introduced
Profile approximations become obsolete
Efficiency shown for additive/subtractive produced MS and filters







Thank you! Questions?

